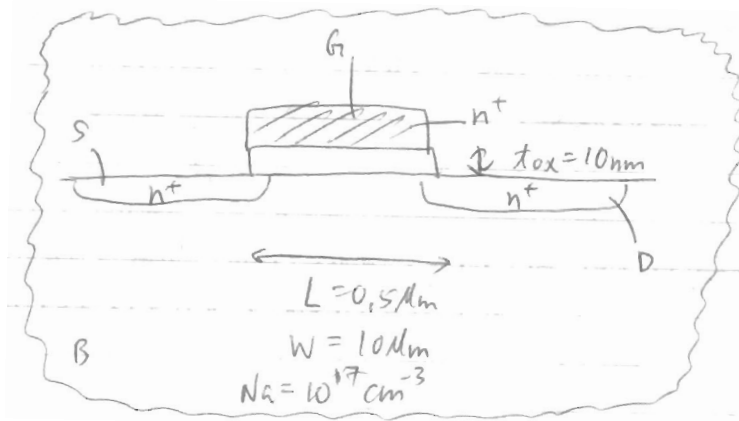


HW #5

①



$$V_{GS} = 2V$$

$$V_{DS} = 2V$$

$$V_{BS} = 0V$$

(a)

$$V_{Tn} = V_{FB} - 2\phi_p - \frac{Q_{B,max}}{C_{ox}}$$

$$V_{FB} = \phi_p - \phi_{nt} = -60mV \log \frac{10^{17}}{10^{10}} - (+550mV) = \underline{-970mV}$$

$$\phi_p = -60mV \log \frac{10^{17}}{10^{10}} = \underline{-420mV}$$

$$Q_{B,max} = -\sqrt{2q\epsilon_s N_a |2\phi_p|} = -\sqrt{2(1.6 \times 10^{-19} C)(11.7 \times 8.85 \times 10^{-14} F/cm)(10^{17} cm^{-3})(2 \times 420mV)}$$

$$= \underline{-1.67 \times 10^{-7} C/cm^2}$$

$$C_{ox} = \frac{\epsilon_{ox}}{t_{ox}} = \frac{3.9 \times 10^{-14} \times 8.85 F/cm}{1 \times 10^{-6} cm} = \underline{3.45 \times 10^{-7} F/cm^2}$$

$$V_{Tn} = -970mV + 2(420mV) + \frac{1.67 \times 10^{-7} C/cm^2}{3.45 \times 10^{-7} F/cm^2}$$

$$V_{Tn} = \underline{0.35V}$$

$$V_{GS} > V_{Tn} \quad \checkmark$$

$$V_{DS} > V_{GS} - V_{Tn} \quad \checkmark$$

$$\Rightarrow \text{saturation}$$

(b)

$$Q_N = -C_{ox} (V_{GS} - V_{Tn})$$

$$Q_N = -3.45 \times 10^{-7} F/cm^2 (2V - 0.35V) = \underline{-5.69 \times 10^{-7} C/cm^2}$$

$$e^- \text{ conc} = \frac{Q_N}{-q} = \frac{-5.69 \times 10^{-7} C/cm^2}{-1.6 \times 10^{-19} C}$$

$$e^- \text{ conc} = \underline{3.56 \times 10^{12} /cm^2}$$

(c) $V_{GS} > V_{Tn} \Rightarrow$ MOS is in inversion

$$Q_{B,max} = -q N_a X_{d,max}$$

$$X_{d,max} = \frac{Q_{B,max}}{-q N_a}$$

$$X_{d,max} = (-1.67 \times 10^{-7} \text{ C/cm}^2) / [-1.6 \times 10^{-19} \text{ C} \times 10^{17} \text{ cm}^{-3}]$$

$$\boxed{X_{d,max} = 1.04 \times 10^{-5} \text{ cm}}$$

(d) cutoff $\Rightarrow V_{GS} < V_{Tn}(V_{BS})$

$$V_{Tn} > 2V$$

$$V_{Tn} = V_{T0n} + \gamma_n \left(\sqrt{-V_{BS} - 2\phi_p} - \sqrt{-2\phi_p} \right)$$

$$\gamma_n = \frac{\sqrt{2q\epsilon_s N_a}}{C_{ox}} = \frac{\sqrt{2(1.6 \times 10^{-19} \text{ C})(11.7 \times 8.85 \times 10^{-14} \text{ F/cm})(1 \times 10^{17} \text{ cm}^{-3})}}{3.45 \times 10^{-7} \text{ F/cm}^2}$$
$$= 0.53 \sqrt{V}$$

$$V_{Tn} = 0.35V + 0.53\sqrt{V} \left(\sqrt{-V_{BS} + 0.84V} - \sqrt{0.84V} \right) > 2V$$

$$-V_{BS} > 15.4V$$

$$\boxed{V_{BS} < -15.4V}$$

② (a) $V_{Top} = -0.5V$
 $N_d = 10^{17} \text{ cm}^{-3}$

$$V_{Tp} = V_{FB} - 2\phi_n - \frac{Q_{B,max}}{C_{ox}}$$

$$V_{FB} = \phi_n - \phi_{pt} = 60\text{mV} \log \frac{10^{17}}{10^{10}} - (-550\text{mV}) = \underline{970\text{mV}}$$

$$\phi_n = 60\text{mV} \log \frac{10^{17}}{10^{10}} = \underline{420\text{mV}}$$

$$Q_{B,max} = \sqrt{2q \epsilon_s N_d (2\phi_n)} = \underline{1.67 \times 10^{-7} \text{ C/cm}^2} \text{ (from \#1)}$$

$$C_{ox} = \frac{\epsilon_{ox}}{t_{ox}}$$

$$V_{Tp} = -0.5V = 970\text{mV} - 2(420\text{mV}) - \frac{1.67 \times 10^{-7} \text{ C/cm}^2}{\epsilon_{ox} / t_{ox}}$$

$$-0.5V = 0.97V - 0.84V - \frac{1.67 \times 10^{-7} \text{ C/cm}^2 \cdot t_{ox}}{25 \times 8.85 \times 10^{-14} \text{ F/cm}}$$

$$\boxed{t_{ox} = 8.35 \times 10^{-6} \text{ cm}} \Rightarrow \underline{C_{ox} = 2.65 \times 10^{-7} \text{ F/cm}^2}$$

(b) $\gamma_p = \sqrt{2q \epsilon_s N_d / C_{ox}}$

$$\gamma_p = \frac{\sqrt{2(1.6 \times 10^{-19} \text{ C})(11.7 \times 8.85 \times 10^{-14} \text{ F/cm})(1 \times 10^{17} \text{ cm}^{-3})}}{25 \times 8.85 \times 10^{-14} \text{ F/cm}} \left(8.35 \times 10^{-6} \text{ cm} \right)$$

$$\boxed{\gamma_p = 0.687 \sqrt{V}}$$

(c) $V_{SG} = 1.5V, V_{SD} = 1.5V, V_{SB} = 0V$

$$V_{SG} > -V_{Tp} \quad \checkmark$$

$$V_{SD} > V_{SG} + V_{Tp} \quad \checkmark \Rightarrow \underline{\text{saturation}}$$

$$-I_D = \mu_p C_{ox} \left(\frac{W}{2L} \right) (V_{SG} + V_{Tp})^2 (1 + \lambda_p V_{SD})$$

$$\lambda_p = \frac{0.1 \text{ mV}^{-1}}{L}$$

$$\lambda_p = \frac{0.1 \mu\text{m V}^{-1}}{L} = \frac{1 \times 10^{-5} \text{ cm/V}}{1 \times 10^{-4} \text{ cm}} = 0.1 \text{ V}^{-1}$$

$$-I_D = \mu_p C_{ox} \left(\frac{W}{2L} \right) (V_{SG} + V_{TP})^2 (1 + \lambda_p V_{SD})$$

$$-I_D = \left(100 \frac{\text{cm}^2}{\text{V}\cdot\text{s}} \right) (2.65 \times 10^{-7} \frac{\text{F}}{\text{cm}^2}) \left(\frac{30 \mu\text{m}}{2 \times 1 \mu\text{m}} \right) (1.5 \text{V} - 0.5 \text{V})^2 (1 + 0.1 \times 1.5 \text{V})$$

$$\boxed{-I_D = 457 \text{ } \mu\text{A}}$$

(d) $I_{D_n} = +WQ_N(L) v_y(L)$ for NMOS

$-I_{D_p} = +WQ_N(L) v_y(L)$ for PMOS

$$V_c(y) = V_{SG} + V_{TP} - \sqrt{(V_{SG} + V_{TP})^2 - 2(V_{SG} + V_{TP} - \frac{V_{SD}}{2}) V_{SD} \left(\frac{y}{L} \right)}$$

$$V_c\left(\frac{L}{2}\right) = 1.5 + (-0.5) - \sqrt{(1 \text{V})^2 - 2(1 \text{V} - \frac{1.5 \text{V}}{2}) \cdot (1.5 \text{V}) \left(\frac{L/2}{L} \right)}$$

$$\underline{V_c\left(\frac{L}{2}\right) = 0.209 \text{V}}$$

$$Q_N\left(y = \frac{L}{2}\right) = -C_{ox} (V_{GB} - V_{TP}) = -C_{ox} (V_G - V_{\text{channel}} - V_{TP})$$

$$= C_{ox} (V_{SG} - V_{\text{channel}} + V_{TP})$$

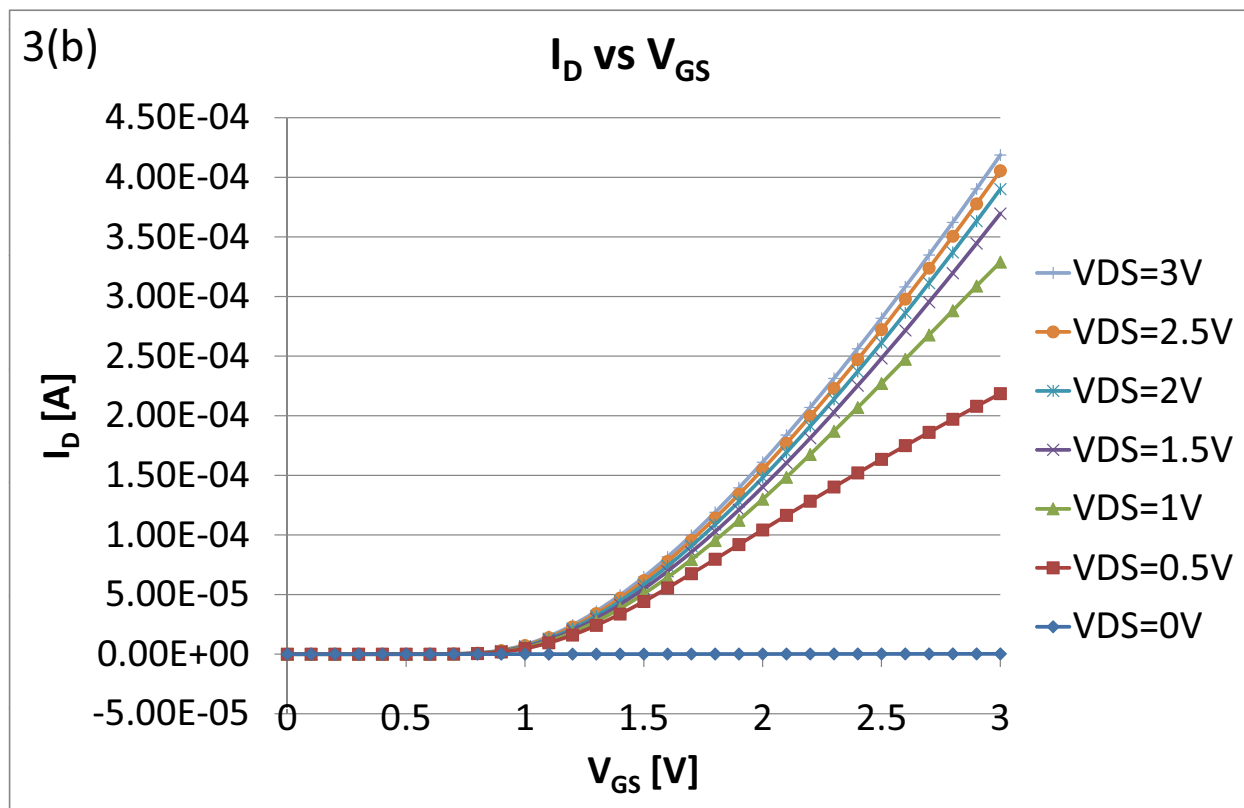
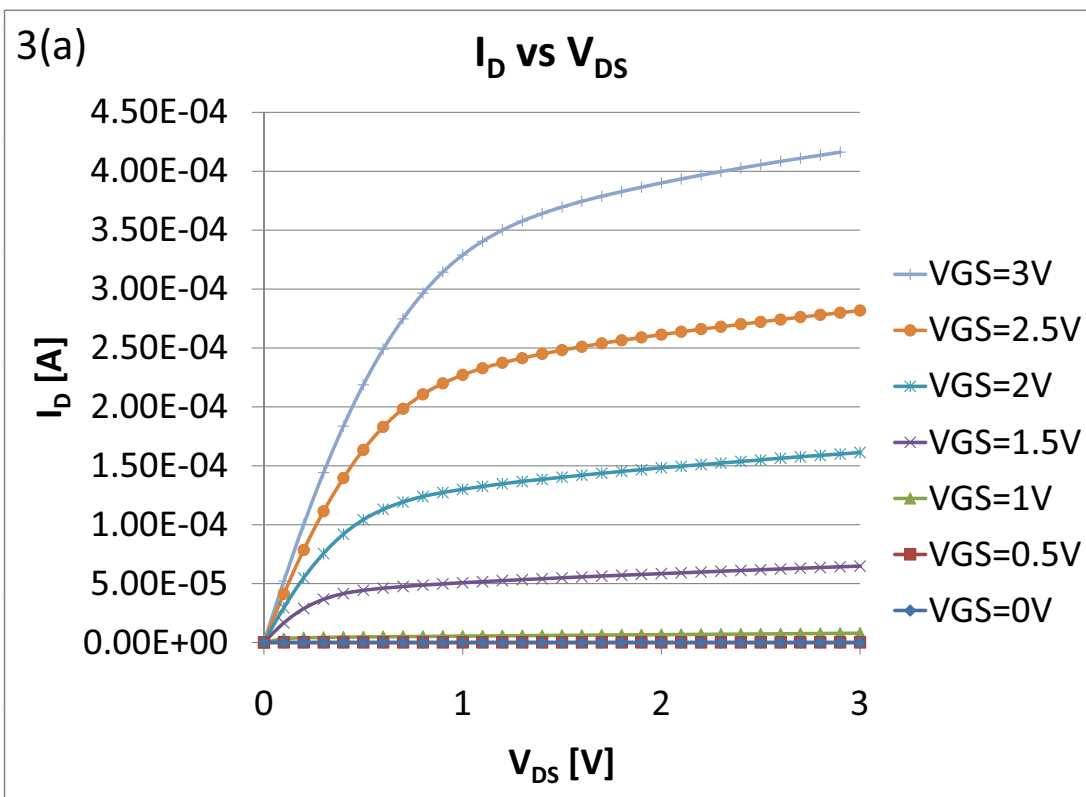
$$= (2.65 \times 10^{-7} \text{ F/cm}^2) (1.5 \text{V} - 0.209 \text{V} - 0.5 \text{V})$$

$$= \underline{2.096 \times 10^{-7} \text{ C/cm}^2}$$

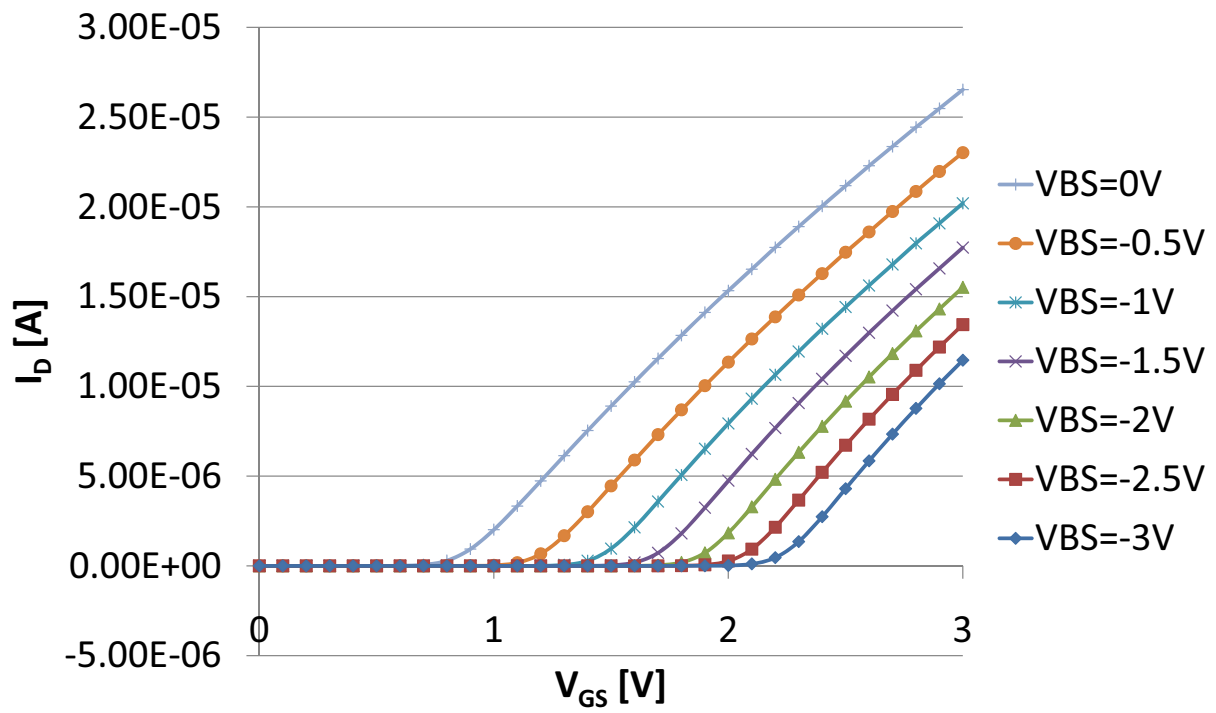
$$457 \mu\text{A} = W Q_N\left(y = \frac{L}{2}\right) v_y\left(\frac{L}{2}\right)$$

$$457 \mu\text{A} = (3 \times 10^{-3} \text{ cm}) (2.096 \times 10^{-7} \text{ C/cm}^2) v_y\left(\frac{L}{2}\right)$$

$$\boxed{v_y\left(\frac{L}{2}\right) = 7.27 \times 10^5 \text{ cm/s}}$$



3(c)

 I_D vs V_{GS} 

3(d)

 V_T vs V_{BS} 